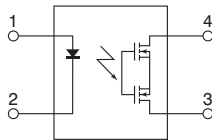




L 2.20mm .087inch
W 2.95mm .116inch
H 1.40mm .055inch



FEATURES

1. This is a new PhotoMOS relay with a SON package* volume ratio approximately 43% that of previous SSOP. Featuring a micro-miniature leadless construction, it makes possible even greater miniaturization and higher density mounting for measuring equipment.

***Small Outline No lead package**
Reduced to approximately 43% volume ratio

2. Size reduction plus low output capacitance and on resistance (C₅R₅) electrical performance achieved at the same time.

Output capacitance (C_{out}): 1.1pF (typ.)
On resistance (R_{on}): 5.5Ω (typ.)

3. High-speed operation at 0.02 ms for both turn on time and turn off time.

TYPICAL APPLICATIONS

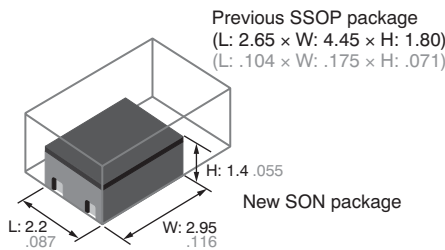
Measuring and testing equipment

1. Test equipment

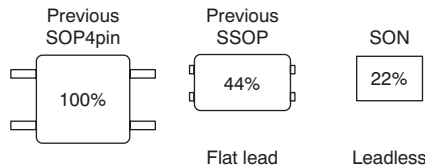
IC tester, Semiconductor performance tester, Probe cards, etc.

2. Board tester

Bare board tester, In-circuit tester, Function tester, etc.



Area comparison (including leads)



TYPES

Type	Output rating*		Tape and reel packing style	
	Load voltage	Load current	Picked from the 1 and 4-pin side	Picked from the 2 and 3-pin side
AC/DC type	25 V	150 mA	AQY221N3MY	AQY221N3MW

Packing quantity: Carton: 3,500 pcs.; Case: 3,500 pcs.

Note: Only tape and reel package is available.

For space reasons, only "1N3" is marked on the product as the part number.

* Indicate the peak AC and DC values.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY221N3M	Remarks
Input	LED forward current	I _F	50mA	
	LED reverse voltage	V _R	5V	
	Peak forward current	I _{FP}	1A	f=100 Hz, Duty factor=0.1%
	Power dissipation	P _{in}	75mW	
Output	Load voltage (peak AC)	V _L	25V	
	Continuous load current (peak AC)	I _L	0.15A	Peak AC,DC
	Power dissipation	P _{out}	250mW	
Total power dissipation		P _T	300mW	
I/O isolation voltage		V _{iso}	200V AC	
Operating temperature		T _{opr}	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures
Storage temperature		T _{sig}	-40°C to +100°C -40°F to +212°F	

RF PhotoMOS (AQY221N3M)

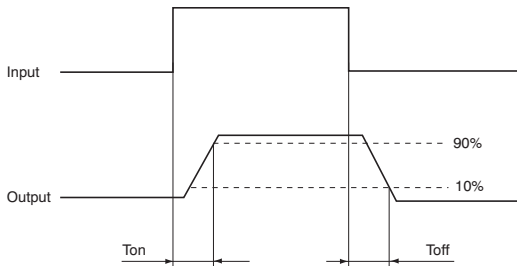
2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQY221N3M	Condition
Input	LED operate current	Typical	1.0 mA	$I_L = 80 \text{ mA}$
		Maximum	3.0 mA	
	LED turn off current	Minimum	0.2 mA	$I_L = 80 \text{ mA}$
		Typical	0.9 mA	
LED dropout voltage	Typical	1.35 V (1.14 V at $I_F = 5 \text{ mA}$)		$I_F = 50 \text{ mA}$
	Maximum	1.5 V		
Output	On resistance	Typical	5.5Ω	$I_F = 5 \text{ mA}$ $I_L = 80 \text{ mA}$ Within 1 s on time
		Maximum	7.5Ω	
	Output capacitance	Typical	1.1 pF	$I_F = 0 \text{ mA}$ $V_B = 0 \text{ V}$ $f = 1 \text{ MHz}$
		Maximum	1.5 pF	
	Off state leakage current	Typical	0.01 nA	$I_F = 0 \text{ mA}$ $V_L = \text{Max.}$
		Maximum	10 nA	
Transfer characteristics	Turn on time*	Typical	0.02 ms	$I_F = 5 \text{ mA}$ $V_L = 10 \text{ V}$ $R_L = 125\Omega$
		Maximum	0.2 ms	
	Turn off time*	Typical	0.02 ms	$I_F = 5 \text{ mA}$ $V_L = 10 \text{ V}$ $R_L = 125\Omega$
		Maximum	0.2 ms	
	I/O capacitance	Typical	0.8 pF	$f = 1 \text{ MHz}$ $V_B = 0 \text{ V}$
		Maximum	1.5 pF	

Notes: 1. Please refer to the schematic and wiring diagram for connection method.

2. Variation possible through combinations of output capacitance and On resistance. For more information, please contact our sales office in your area.

*Turn on/Turn off time



RECOMMENDED OPERATING CONDITIONS

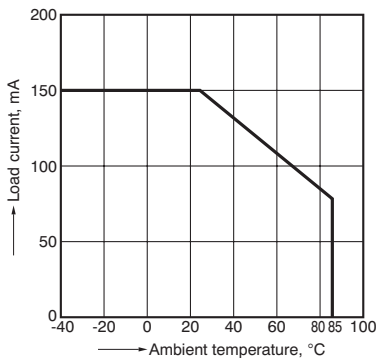
Please obey the following conditions to ensure proper relay operation (turn on) and resetting (turn off).

Item	Symbol	Recommended value	Unit
Input LED current	I_F	5	mA

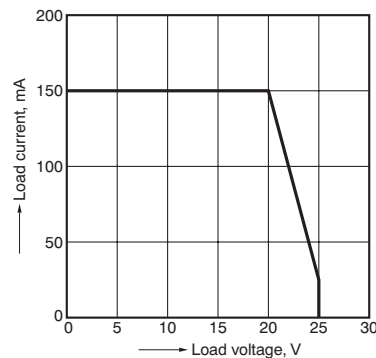
REFERENCE DATA

1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C
-40°F to +185°F

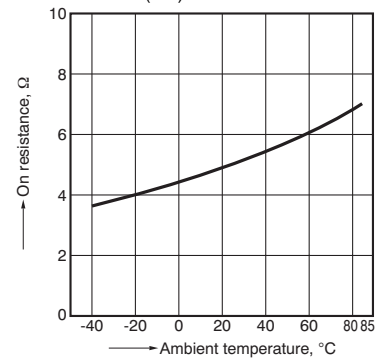


2. Load current vs. Load voltage characteristics
Ambient temperature: 25°C 77°F



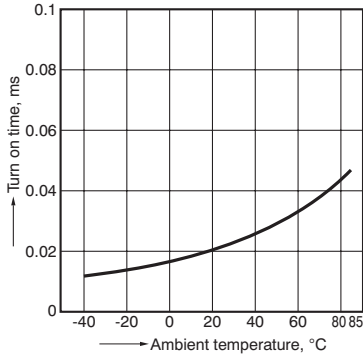
3. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4
LED current: 5 mA; Load voltage: 10V (DC);
Load current: 80mA (DC)



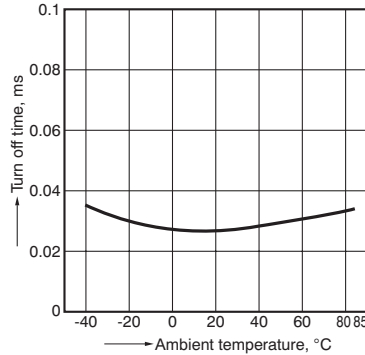
4. Turn on time vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4
LED current: 5 mA; Load voltage: 10V (DC);
Continuous load current: 80mA (DC)



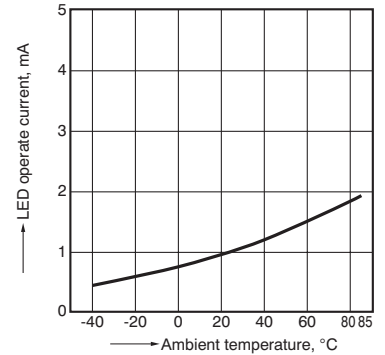
5. Turn off time vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4
LED current: 5 mA; Load voltage: 10V (DC);
Continuous load current: 80mA (DC)



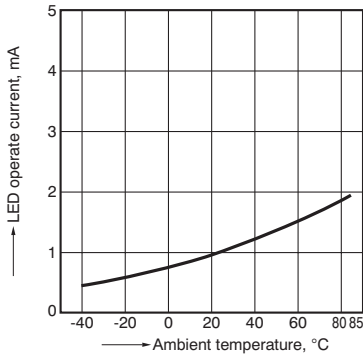
6. LED operate current vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4
Load voltage: 10V (DC);
Continuous load current: 80mA (DC)



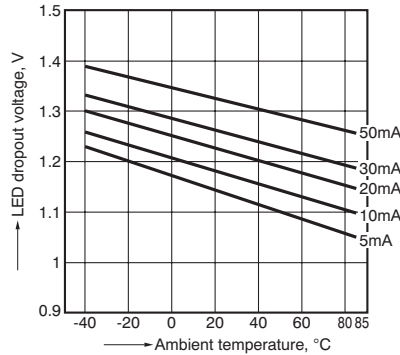
7. LED turn off current vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4
Load voltage: 10V (DC);
Continuous load current: 80mA (DC)



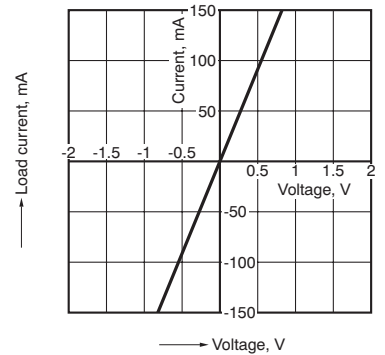
8. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



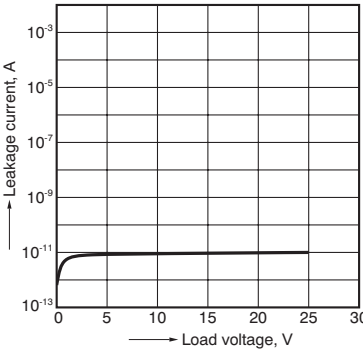
9. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4
Ambient temperature: 25°C 77°F



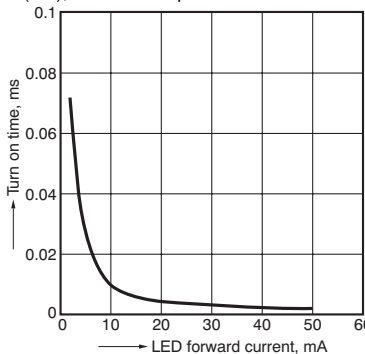
10. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4
Ambient temperature: 25°C 77°F



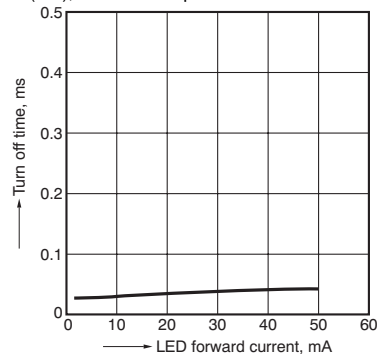
11. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4
Load voltage: 10V (DC); Continuous load current:
80mA (DC); Ambient temperature: 25°C 77°F



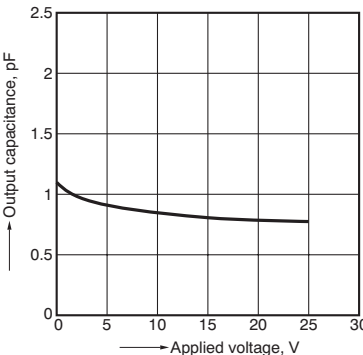
12. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4
Load voltage: 10V (DC); Continuous load current:
80mA (DC); Ambient temperature: 25°C 77°F



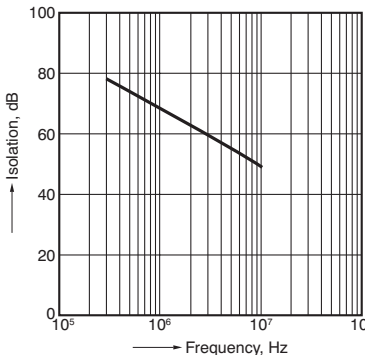
13. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4
Frequency: 1 MHz, 30m Vrms; Ambient temperature:
25°C 77°F



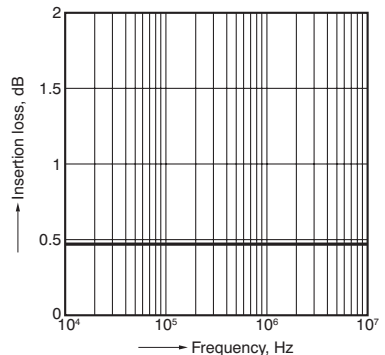
14. Isolation vs. frequency characteristics (50Ω impedance)

Measured portion: between terminals 3 and 4
Ambient temperature: 25°C 77°F



15. Insertion loss vs. frequency characteristics (50Ω impedance)

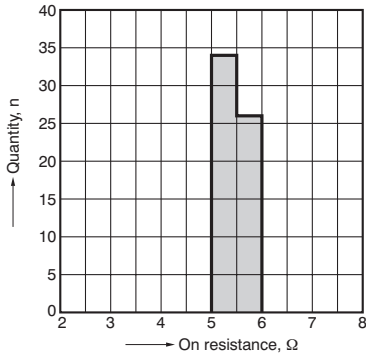
Measured portion: between terminals 3 and 4
Ambient temperature: 25°C 77°F



RF PhotoMOS (AQY221N3M)

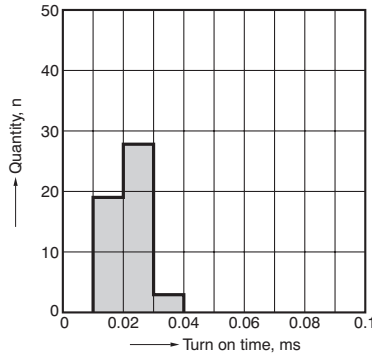
16. On resistance distribution

Measured portion: between terminals 3 and 4
 Continuous load current: 80mA (DC), n: 50pcs.
 Ambient temperature: 25°C 77°F



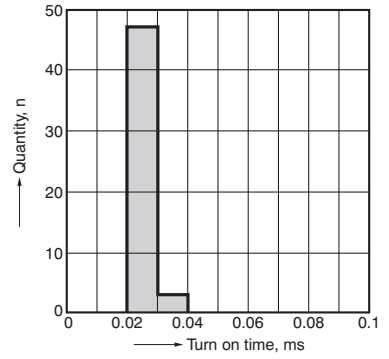
17. Turn on time distribution

Load voltage: 10V (DC)
 Continuous load current: 80mA (DC), n: 50pcs.
 Ambient temperature: 25°C 77°F



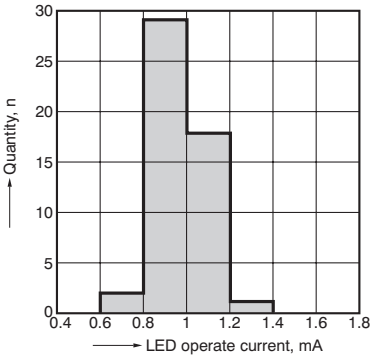
18. Turn off time distribution

Load voltage: 10V (DC)
 Continuous load current: 80mA (DC), n: 50pcs.
 Ambient temperature: 25°C 77°F

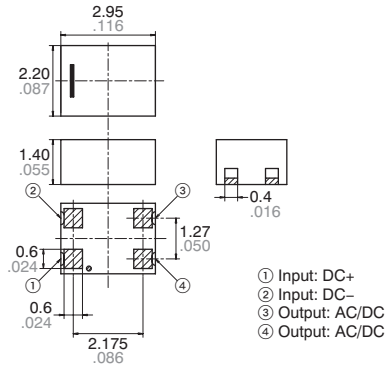


19. LED operate current distribution

Load voltage: 10V (DC)
 Continuous load current: 80mA (DC), n: 50pcs.
 Ambient temperature: 25°C 77°F



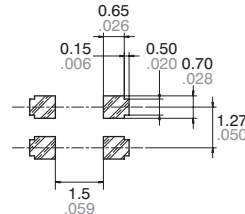
DIMENSIONS (Unit: mm inch)



- ① Input: DC+
- ② Input: DC-
- ③ Output: AC/DC
- ④ Output: AC/DC

General Tolerance: $\pm 0.2 \pm .008$

Recommended mounting pad (Top view)



Tolerance: $\pm 0.1 \pm .004$

SCHEMATIC AND WIRING DIAGRAMS

E₁: Power source at input side; I_F: LED forward current; V_L: Load voltage; I_L: Load current

Schematic	Output configuration	Load	Con-nection	Wiring diagram
	1a	AC/DC	—	

Cautions for Use

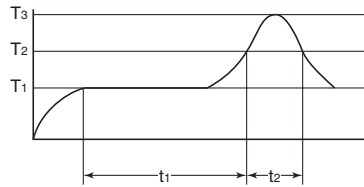
1. Derated designs

Consideration of reliability is absolutely imperative for derated designs because of its importance to the working lifetime of the product.

Please be sure to derate sufficiently from the maximum rating of the relay when designing a system. Be sure to conduct real-life testing of the product; and, if necessary, provide extra leeway against the maximum rating by taking sufficiently safety measures.

2. Soldering

- Example of recommended soldering conditions
IR (Infrared reflow) soldering method



T₁ = 150 to 180°C 302 to 356°F
 T₂ = 230°C 446°F
 T₃ = 245°C 473°F or less
 t₁ = 60 to 120 s or less
 t₂ = 30 s or less

- When using lead-free solder, we recommend a type with an alloy composition of Sn 3.0 Ag 0.5 Cu. Please inquire about soldering conditions and other details.
- The temperature profile indicates the temperature of the soldered terminal on the surface of the PC board. The ambient temperature may increase excessively. Check the temperature under mounting conditions.

3. Transportation and storage

1) Extreme vibration during transport will damage the relay. Handle the outer and inner boxes with care.

2) PhotoMOS relays implemented in SON type are sensitive to moisture and come in sealed moisture-proof packages. Observe the following cautions on storage.

- After the moisture-proof package is unsealed, take the devices out of storage as soon as possible (within 1 month, less than 45°C 113°F/70% R.H.).

- If the devices are to be left in storage for a considerable period after the moisture-proof package has been unsealed, it is recommended to keep them in another moisture-proof bag containing silica gel (within 3 months at the most).

3) Storage under extreme conditions will cause soldering degradation, external appearance defects, and deterioration of the characteristics. The following storage conditions are recommended:

- Temperature: 0 to 45°C 32 to 113°F
- Humidity: Less than 70% R.H.
- Atmosphere: No harmful gasses such as sulfurous acid gas, minimal dust.